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The first-principles study of the adsorption of NH_3 , NO, and NO_2 gas molecules on InSe-like phosphorus carbide[†]

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Introduction

Ultrathin two-dimensional (2D) materials possess a high surface area-to-volume ratio and weak screening of electrons, which make them vulnerable to the influence of the ambient physical and chemical adsorbates.^{1,2} On the other hand, the advanced chemical activity of 2D materials offers the possibility to modify their electronic and chemical properties by the effect of ambient adsorbates.3 The high sensitivity of the 2D materials to environmental molecules and gases also makes them promising for gas adsorption and detection.⁴ For instance, first-principles calculations have predicted a strong binding of the NO and NO2 gas molecules to MoS₂.⁵ The MoS₂ monolayer produced by annealing sputtered Mo films in S vapor has shown excellent selectivity to NH₃.⁶ Many investigations indicate potential for InSe in fabricating gas sensors.^{7,8} Particularly, the strong ability of InSe to interact with external NH₃, NO₂, and NO molecules has been found.⁹ It should be noted that the InSe surface degrades as a result of defect-photopromoted oxidations, which may reduce its applications.¹⁰

The discovery of new 2D materials, such as phosphorene, has shown that these materials may provide much stronger adsorption ability to ambient molecules and gases compared to MoS_2 or InSe.^{9,11–13} The promoted activity of phosphorene has been reported for the NO, NO₂, NH₃, and CO molecules.^{14,15} In addition, the gas sensing ability of phosphorene has been improved by the doping of its surface by NH₃ and NO₂ gas molecules.¹⁶ However, such high chemical activity of phosphorene leads to its

The adsorption of environmental gas molecules, *i.e.*, NH₃, NO, and NO₂ on the γ -PC surface has been studied using first-principles calculations. The lowest-energy configurations of these molecules on the γ -PC surface were found and the adsorption energies were calculated. The NH₃, NO, and NO₂ molecules were found to be physisorbed on the γ -PC surface. The analysis of the charge transfer between the molecules and the surface predicted NH₃ and NO as donors to γ -PC, while NO₂ acted as an acceptor to γ -PC. Remarkable changes in the band structure of γ -PC were found upon the adsorption of NO₂ on its surface. In addition, significant modulations in the work function of γ -PC were observed after the adsorption of NH₃ and NO.

fast degradation in ambient conditions.¹⁷ In addition, the formation of defects on the phosphorene surface may lead to the degradation of its structure.¹⁸ Nevertheless, the adsorption of different adatoms on phosphorene including s and p valence metals, 3d transition metals, noble metals, H and O does not necessarily disturb its structural integrity.^{19,20}

In the search of 2D materials that are highly sensitive to gases while remaining structurally stable in ambient conditions, considerable research has focused on the study of 2D hybrid materials.²¹ Phosphorus carbide (PC), a composite of graphene and phosphorene, is one of these materials.^{22,23} The latest studies show that PC has an anisotropic structure, wide band gap, and high charge carrier mobility.²⁴ Furthermore, PC-based field-effect transistors have been fabricated recently *via* a novel carbon doping technique.²⁵ More importantly, PC combines the high chemical activity existing in phosphorene and the structural stability inherent to graphene, which are the most important features of all gas sensors.^{24,26,27} Previous studies on the sensing mechanism of 2D layered materials, including monolayer MoS_2 ,²⁸⁻³⁰ monolayer SnS_2 ,³¹ and monolayer C_3N ,³² indicate that charge transfer plays an important role for the sensing of gas molecules.

Very recently, stable γ -PC with an InSe-like structure has been predicted theoretically.³³ This PC allotrope possesses the promoted adsorption and low diffusion barrier of Li, which render its application in rechargeable nanodevices. However, to date, the possible effects of ambient adsorbates on the structure and electronic properties of γ -PC as well as the suitability of γ -PC for gas detection have not been investigated.

In this work, first-principles calculations have been performed for the adsorption of NH_3 , NO, and NO_2 molecules on γ -PC. Their exact configurations on the surface and their preferential binding

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Results and discussion

The top and side views of the unit cell of the optimized γ -InSelike phosphorus carbide (γ -PC) are shown in Fig. 1a. The calculated lattice constants of γ -PC were a = 3.09 Å and b = 5.35 Å, and the lengths of the C–C and C–P bonds were 1.56 and 1.97 Å, respectively, which were comparable with those reported in the theoretical study of γ -PC.³³ The band structure of γ -PC obtained by the GGA PBE (black) and HSE06 (red) methods is presented in Fig. 1b. Importantly, both methods predicted γ -PC to be an indirect band gap semiconductor. The GGA PBE approach only slightly underestimated the band gap value (1.51 eV) compared to that (2.58 eV) calculated using the HSE method, which was also consistent with previously reported results.³³ Therefore, the less expensive computational method was used in this work.

To determine the lowest-energy adsorption position of the NH₃, NO, and NO₂ molecules on γ -PC, several possible configurations of the molecules in all possible adsorption sites and aligned parallel, perpendicular or tilted to the surface plane of γ -PC were investigated. The calculated adsorption energy (*E*_a) values of NH₃, NO, and NO₂ on γ -PC, the charge transfer (Δq) between the adsorbed molecules and the γ -PC surface, the shortest distance (*d*) from the adsorbed molecules to the γ -PC surface, and the work function of the molecule-adsorbed γ -PC for the most stable adsorption configurations are given in Table 1. Several other examined configurations of the considered

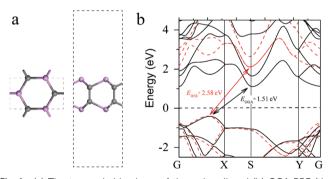


Fig. 1 (a) The top and side views of the unit cell and (b) GGA PBE (the black line) and HSE (the red line) band structures of γ -PC.

Table 1 The adsorption energy (E_a) of NH₃, NO, and NO₂ on γ -PC and MoS₂34 and InSe⁹ (reference data); the charge transfer (Δq) between the adsorbed molecules and the γ -PC surface; the shortest distance (d) from the adsorbed molecules to the γ -PC surface; the work function (WF) of molecule-adsorbed γ -PC

Molecule	u)	<i>E</i> _a , eV InSe		Role	$\Delta q, e$	d, Å	WF, eV
NH ₃ NO NO ₂	$-0.54 \\ -0.94$	-0.13	-0.20	Donor Donor Acceptor		2.90 3.01 2.88	4.71 5.61
No molecule	—	—	—	_ `	—	—	5.6

molecules on γ -PC with comparably lower E_a are shown in Fig. S1–S3 (see ESI[†]) and the E_a , d, and Δq values for these structures are presented in Table S1 (see ESI[†]).

NH₃ adsorption

The lowest-energy configuration of an NH₃ molecule on the γ -PC surface is shown in Fig. 2a. The molecule was located above the centre of the hollow hexagon with the three H atoms pointing away from the surface. After adsorption, the shortest distance (*d*) between the N atom of the molecule and the surface was 2.90 Å, and the H–N bonds elongated to 1.023 Å compared to those of a free NH₃ gas molecule (1.01 Å). This elongation of bond lengths was mostly attributed to the transfer of electron density from the old bonds to the newly formed bonds between NH₃ and γ -PC.³⁵ The adsorption energy (*E*_a) of the NH₃ molecule on the γ -PC surface was -0.17 eV, which suggested that the physisorption behaviour of NH₃ on γ -PC was similar to that of NH₃ on InSe (*E*_a = -0.20 eV);⁹ however, on MoS₂, the NH₃ molecule possessed about 2 times lower *E*_a (-0.49 eV).³⁴

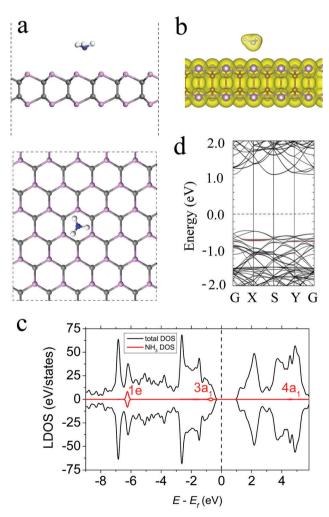


Fig. 2 (a) The side and top views, (b) total electron density plot, (c) LDOS, and (d) band structure of NH₃-adsorbed γ -PC. The black dashed line shows the Fermi level. The isosurface value is set to 0.05 e Å⁻³. The bands and DOS coloured in red correspond to the NH₃ molecule.

The Bader charge transfer analysis indicated that NH₃ acted as an electron donor to γ -PC and the amount of charge transferred from the molecule to the surface was 0.028 *e*; however, on InSe⁹ and MoS₂,^{34,36} the NH₃ molecule played the role of an electron acceptor. Additional differential charge density (DCD) analysis (Fig. S4, ESI[†]) indicated a slight depletion of the electrons in the NH₃ molecule and the accumulation of electrons at the P atoms near the surface. This is mainly due to the ionization of the lone pair of electrons on the N atom in the 3a₁ state. The total electron density plot (Fig. 2b) indicates the zero-electron density in the interface region between the NH₃ molecule and the γ -PC surface, which suggests non-covalent bonding between the molecule and the surface. In other considered configurations (Fig. S1, ESI[†]) also, NH₃ is a weak donor to γ -PC (Table S1, ESI[†]).

The results for the total and local density of states (LDOS) of the NH₃ molecule adsorbed on γ -PC are presented in Fig. 2c. The contribution of the molecule to the total DOS of γ -PC was far from the Fermi level, which confirmed the physisorption of NH₃ on γ -PC. The non-bonding 3a₁ state broadened and appeared slightly below the valence band maximum (VBM); this is also seen in the band structure in Fig. 2d and reflects the charge transfer. In addition, the adsorption of the NH₃ molecule decreased the work function of γ -PC from 5.61 to 5.46 eV.

NO adsorption

For NO adsorption on γ -PC, the most energetically favourable structure is shown in Fig. 3a, where the N–O bond of the molecule is tilted to the surface and is located at d = 3.01 Å above the centre of the hexagon. The N–O bond of the molecule elongated compared to that of the free NO gas molecule from 1.010 to 1.167 Å after adsorption. This elongation of the bond is mostly attributed to the transfer of electron density from the old bond to the newly formed bond between NO and γ -PC.³⁵ The E_a value is -0.20 eV for NO adsorbed on γ -PC, indicating a non-covalent interaction between the molecule and the surface, which is also confirmed by the zero-electron density in the interface region between the NO molecule and the γ -PC surface (Fig. 3b). It should be noted that the E_a of NO on γ -PC was lower than that of NO on InSe⁹ but was higher than that of NO on MOS₂.³⁴

The Bader analysis predicted NO to be a weak electron donor to γ -PC with the amount of charge transferred from the molecule to the surface being 0.003 *e*. Interestingly, on both InSe and MoS₂, the NO molecule is an electron acceptor.^{9,34} To understand this specific sensitivity of γ -PC to NO the electron localization function of the NO-adsorbed γ -PC was plotted (Fig. S5a, ESI†). It was found that there was strong charge redistribution within the molecule, while a very little amount of charge was transferred to the nearest P atom at the surface. It was also found that the acceptor/donor role of the NO molecule to γ -PC mostly depended on its position on the surface. More details are presented in ESI.†

Fig. 3c presents the LDOS of the NO molecule adsorbed on the γ -PC surface. It can be seen that the half-filled 2π frontier state is doubly degenerated and the 2π down state is located between the Fermi level and the conduction band minimum (CBM); this is also depicted in the band structure plot in Fig. 3d. The presence of unoccupied states within the band

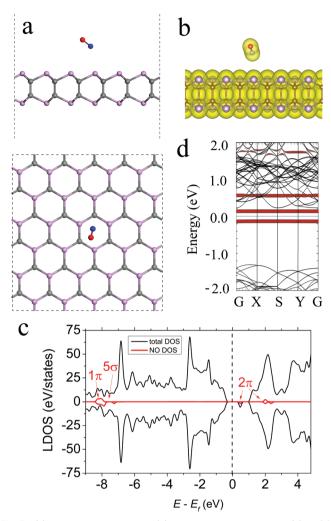


Fig. 3 (a) The side and top views, (b) total electron density plot, (c) LDOS, and (d) band structure of NO-adsorbed γ -PC. The black dashed line shows the Fermi level. The isosurface value is set to 0.05 e Å⁻³. The bands and DOS coloured in red correspond to the NO molecule.

gap of NO-adsorbed γ -PC but a weak charge flow between the molecule and the surface may explain the significant decrease in the work function of γ -PC from 5.61 to 4.71 eV upon NO adsorption.

NO₂ adsorption

The most energetically preferable configuration of the NO₂ molecule on the γ -PC surface is shown in Fig. 4a. The molecule was located above the C–P bond at d = 2.88 Å with the N–O bonds pointing towards the surface. These N–O bonds slightly elongated to 1.217 Å compared to those of the free NO₂ gas molecule (1.20 Å). This elongation of bonds is mostly attributed to the transfer of electron density from the old bonds to the newly formed bonds between NO₂ and γ -PC.³⁵ The E_a value was -0.55 eV for NO₂ on γ -PC; it was ~ 2.3 times lower than that of NO₂ on InSe ($E_a = -0.24$ eV)⁹ but was ~ 1.7 times higher than that of NO₂ molecule on the γ -PC surface, the zero-electron density in their interface region (Fig. 4b) designates the non-covalent nature of the interaction.

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The electron localization function analysis (Fig. S5b, ESI[†]) and the calculated charge of 0.091 *e* transferred from the γ -PC surface to the NO₂ molecule indicated the strong acceptor ability of the molecule. The charge transfer from γ -PC to NO₂ occurred through orbital hybridization, which simultaneously induced a magnetic moment of about 0.99 $\mu_{\rm B}$ in γ -PC. A more detailed explanation of the acceptor nature of the NO₂ molecule on γ -PC is presented in the ESI[†] (Fig. S3 and Table S1). Similarly, NO₂ has been found to be a strong acceptor for InSe⁹ and MoS₂.³⁴ The value of the work function of γ -PC remained almost unchanged after the adsorption of NO₂, which indicated that the transfer of electrons to the vacuum level was not hindered.

The LDOS and band structure, shown in Fig. 4c and d, respectively, indicate the spin splitting of the $6a_1$ orbital of NO₂ due to its adsorption on γ -PC. Particularly, the $6a_1$ spin-up state is ~0.60 eV below the Fermi level, while the $6a_1$ spin-down state is ~0.50 eV above the Fermi level. The 4b₁ and 1a₂

b

d

Energy (eV)

2.0

1.0

-1.0

-2.0

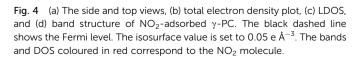
G X S

5b

2

4

YG



-4

-2

 $E - E_{f}(eV)$

0

total DOS

1а

orbitals also exhibit spin splitting and coincide with the valence states of γ -PC. Such strong orbital mixing accounts for the charge transfer between NO₂ and γ -PC.

For applications in gas sensors and detectors, the recovery time of sensing materials is an important parameter.^{28,32} Therefore, the recovery time of γ -PC was also calculated. It was found that at the room temperature of 300 K, the recovery times for NH₃, NO, and NO₂ on γ -PC were about 0.4 \times 10⁻⁹, 2.3 \times 10⁻⁹, and 2.8 \times 10⁻³ s, respectively. This fast recovery time of γ -PC suggests that it is a promising reversible material for room-temperature gas sensors.

Methods

The simulations were based on the density functional theory (DFT), as implemented in the Vienna ab initio simulation package (VASP).37 The exchange correlation interaction was described by the generalized gradient approximation (GGA) with the Perdew, Burke and Ernzerhof (PBE) functional.³⁸ The hybrid Heyd-Scuseria-Ernzerhof (HSE06) functional was employed for the test calculations of the electronic structure of the γ -PC unit cell.³⁹ To obtain a better description of the long-range van der Waals interactions between the surface and gas molecules, the van der Waals-corrected functional with Becke88 optimization was used. The Brillouin zone sampling for k-points was based on a $6 \times 6 \times 1$ Monkhorst-Pack grid. The atomic positions were relaxed until the force on each atom was smaller than 0.01 eV Å⁻¹. The simulated system of a 5 \times 3 \times 1 supercell was created with the vacuum space in the z-direction larger than 15 Å to avoid interactions with the neighbouring super cells. The kinetic energy cut-off for the plane wave expansion was set to 400 eV. The adsorption energy of gas molecules on the γ -PC surface was calculated as follows:

$$E_{\rm a} = E_{\rm PC/mol} - E_{\rm PC} - E_{\rm mol},\tag{1}$$

here, $E_{PC/mol}$ is the total energy of the molecule-adsorbed γ -PC system, and E_{PC} and E_{mol} are the total energies of pristine γ -PC and a free gas molecule, respectively.

Bader analysis⁴⁰ was conducted to estimate the charge flow between the γ -PC surface and gas molecules. The work function was calculated as the difference between the electrostatic potentials of an electron at points remote from the surface and the Fermi level.

According to the conventional transition state theory, the recovery time^{32,41} (τ) can be expressed as follows:

$$\tau = \nu^{-1} \mathbf{e}^{(-E_{\rm a}/K_{\rm B}T)},\tag{2}$$

here, *T* is the temperature, $K_{\rm B}$ is the Boltzmann constant, ν is the attempt frequency (10¹² s⁻¹),⁴¹ and the desorption energy barrier can be approximated as the adsorption energy $E_{\rm a}$.^{32,41}

Conclusions

The calculated low adsorption energies of the NH₃, NO, and NO₂ molecules on the γ -PC surface suggested strong interactions between γ -PC and these molecules. In all the considered cases, the molecules were physiosorbed on γ -PC, which suggested that

a

С

LDOS (eV/states)

75

50

25 0

-25

-50 -75

-8

-6

they may easily desorb from its surface. Due to this, γ -PC possessed a short recovery time. In addition, the adsorption abilities of NH₃, NO, and NO₂ on γ -PC were superior to those on InSe but lower than those on MoS₂. The physisorption of NO and NO₂ led to a remarkable change in the band structure of γ -PC. Hence, the presence of these molecules on its surface could be detected. Moreover, the physisorption of NH₃ and NO induced significant modulations in the work function of γ -PC.

Conflicts of interest

There are no conflicts to declare.

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